Data Sheet N2081, Rev.-

SBS540

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SBS540 SCHOTTKY RECTIFIER



Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Disk drives
- Battery charging

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	40	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _c =80°C, rectangular wave form	5	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse, T_C =25°C	150	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 5A, Pulse, T _J = 25 °C	0.48	0.65	V
	V _{F2}	@ 5A, Pulse, T _J = 125 °C	0.44	0.63	V
Reverse Current*	I _{R1}	$@V_R$ = Rated V _R , Pulse, T _J = 25 °C	0.03	1.0	mA
	I _{R2}	$@V_R$ = Rated V _R , Pulse, T _J = 125 °C	18	30	mA
Junction Capacitance	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	180	200	pF

* Pulse width < 300 µs, duty cycle < 2%

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Technical Data Data Sheet N2081, Rev.-

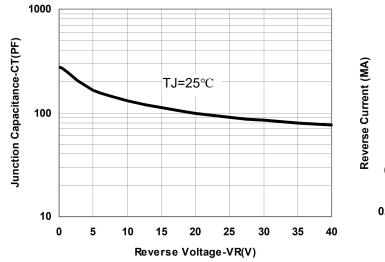
SBS540

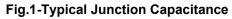
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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +125	°C
Storage Temperature	T _{stg}	-	-55 to +125	°C
Typical Thermal Resistance Junction to Lead	$R_{ ext{ heta}JL}$	DC operation	12	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$	DC operation	111	°C/W
Approximate Weight	wt	-	1.02	g







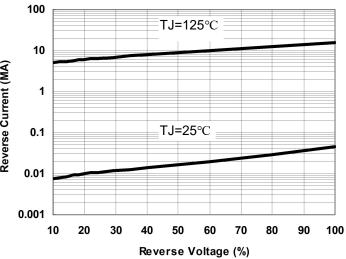
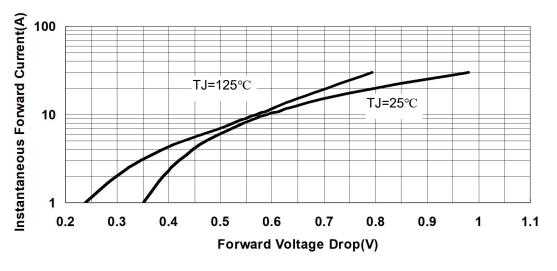


Fig.2-Typical Reverse Current





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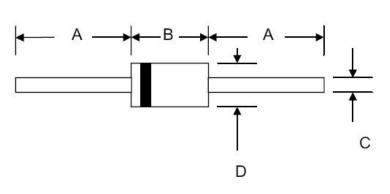


Technical Data Data Sheet N2081, Rev.-

SBS540



Mechanical Dimensions DO-201AE



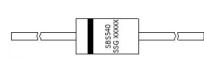
SYMBOL	Millim	Millimeters		hes
SYMBOL	Min.	Max.	Min.	Max.
А	25.4	-	1.000	-
В	7.20	9.50	0.283	0.374
С	0.94	1.07	0.037	0.042
D	4.80	5.30	0.189	0.209

Ordering Information

Device Package		Shipping
SBS540	DO-201AE(Pb-Free)	3000pcs / tape
SBS540TA	DO-201AE(Pb-Free)	3000pcs / tape

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

SBS540

SSG

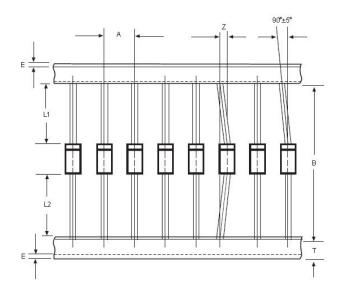
YY WW

L

- = Part Name = SSG = Year
 - = Week
- = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification DO-201AE



SYMBOL	Millimeters		
STWBOL	Min.	Max.	
A	9.50	10.50	
В	50.9	53.9	
Z	-	1.20	
Т	5.60	6.40	
E	_	0.80	
IL1-L2I	_	1.0	



Technical Data Data Sheet N2081, Rev.-



SBS540

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